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***Iron oxide***

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***Magnesium oxides***

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***Nitrides***

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*Stepped single crystal surfaces*

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*Insulating surfaces*

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F. Malengreau, V. Hautier, M. Vermeersch, R. Sporken and R. Caudano, Chemical interactions at the interface between aluminium nitride and iron oxide determined by XPS 330 (1995) 75

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***Oxide–water interfaces***

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